

APPLICATION MANUAL



OPAMP with Full-swing Output TK17016/18S

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OPAMP with Full-swing Output TK17016/18S

1. DESCRIPTION

The TK17016/18S is an operational amplifier with full-swing output.

The features are low voltage operation, low saturation output, and a small package.

It is suitable for use with portable equipment.

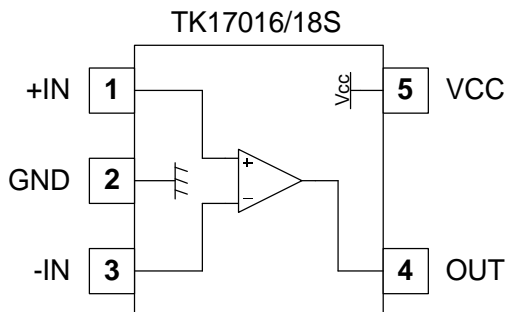
2. FEATURES

- Low Voltage Operation $V_{OP}=2V$ to $10V$
- Low Saturation Output Voltage $V_{OM}=V_{CC}-0.2V$
- Slew Rate $SR=4V/\mu\text{sec}$
- Unity Gain Bandwidth $GB=12\text{MHz}$
- Small Package SOT23-5

3. APPLICATIONS

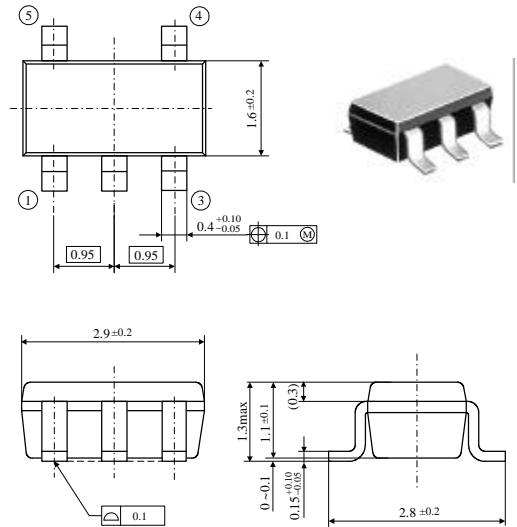
- General Purpose
- Portable Equipment
- Low Operating Voltage Equipment

4. PIN CONFIGURATION



5. PACKAGE OUTLINE

■ SOT23-5



Unit : mm

6. ABSOLUTE MAXIMUM RATINGS

Parameter	Symbol	Rating	Units	Conditions
Supply Voltage	V_{CC}	12	V	
Power Dissipation	P_D	200	mW	*
Storage Temperature Range	T_{stg}	-55 ~ +150	°C	
Operating Temperature Range	T_{OP}	-40 ~ +85	°C	
Operating Voltage Range	V_{OP}	2 ~ 10	V	

* P_D must be decreased at the rate of $1.6\text{mW}/^\circ\text{C}$ for operation above 25°C .

7. ELECTRICAL CHARACTERISTICS

$V_{CC}=5V, T_a=25^{\circ}C$

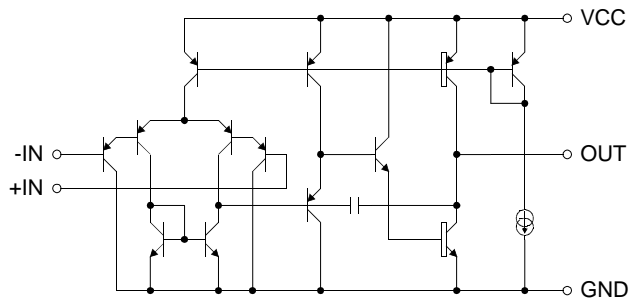
Parameter	Symbol	Value			Units	Conditions
		MIN	TYP	MAX		
Supply Current	I_{CC}	-	2	3	mA	$R_L=\infty, V_{in}=V_{CC}/2$
Input Offset Voltage	V_{IO}	-	0.5	6	mV	
Input Offset Current	I_{IO}	-	1	50	nA	
Input Bias Current	I_{IB}	-	100	300	nA	
Common-Mode Input Voltage Range (TK17016S)	V_{ICMR}	0~ $V_{CC}-1.5$	-	-	V	
Common-Mode Input Voltage Range (TK17018S)	V_{ICMR}	0.5~ $V_{CC}-1$	-	-	V	
Maximum Output Voltage	V_{OM}	$V_{CC}-0.3$	$V_{CC}-0.1$	-	V	$R_L \geq 5k\Omega, V_{IN+}=3V, V_{IN-}=2V$
		-	0.1	0.3	V	$R_L \geq 5k\Omega, V_{IN+}=2V, V_{IN-}=3V$
Source Current	I_{SO}	0.7	1.2	-	mA	$V_{IN+}=3V, V_{IN-}=2V$
Sink Current	I_{SI}	8	25	-	mA	$V_{IN+}=2V, V_{IN-}=3V$
Common-Mode Rejection Ratio	CMRR	60	85	-	dB	
Supply Voltage Rejection Ratio	SVRR	60	100	-	dB	
Open Circuit Voltage Gain	G_{VO}	60	100	-	dB	$R_L \geq 10k\Omega$
Slew Rate	SR	-	4	-	V/ μ s	$A_V=1, V_{IN}=1V_{P-P}$
Gain-Bandwidth Product	GB	-	12	-	MHz	$f=10kHz$

* Note: This amplifier may oscillate when used as a buffer with a capacitive load.

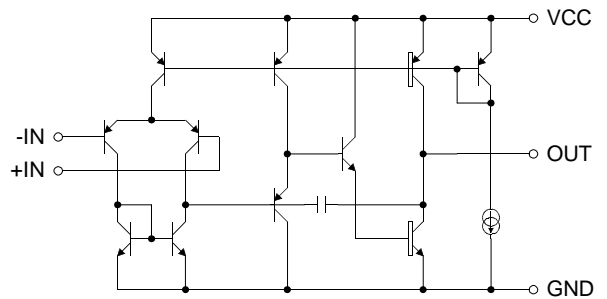
* A practical gain range for this amplifier is from 3dB to 30dB.

8. SIMPLIFIED SCHEMATIC

• TK17016S

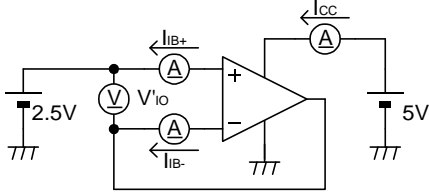


• TK17018S



9. TEST CIRCUIT

- Supply Current, Input Offset Voltage, Input Offset Current, Input Bias Current

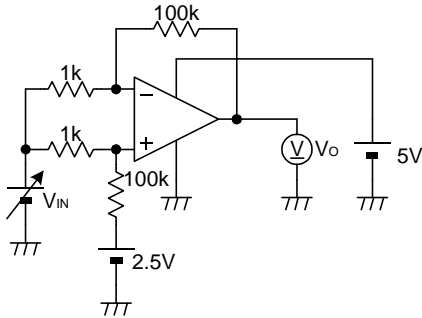


$$V_{IO} = |V'_{IO}|$$

$$I_{IO} = |I_{IB+} - I_{IB-}|$$

$$I_{IB} = \frac{I_{IB+} + I_{IB-}}{2}$$

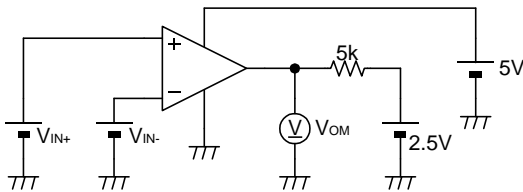
- Common-Mode Rejection Ratio, Common-Mode Input Voltage Range



$$CMRR = 20 \log \left(101 \times \left| \frac{\Delta V_{IN}}{\Delta V_O} \right| \right)$$

$$V_{ICMR} : CMRR > 60dB$$

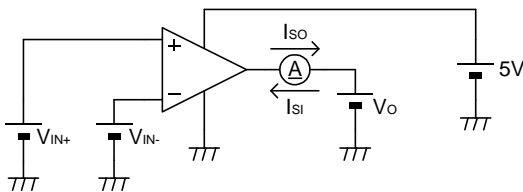
- Maximum Output Voltage



$$V_{OM+} : V_{IN+} = 3V, V_{IN-} = 2V$$

$$V_{OM-} : V_{IN+} = 2V, V_{IN-} = 3V$$

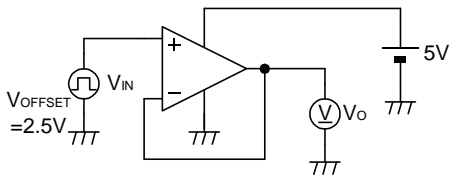
- Source Current, Sink Current



$$I_{SO} : V_{IN+} = 3V, V_{IN-} = 2V, V_O = 4.5V$$

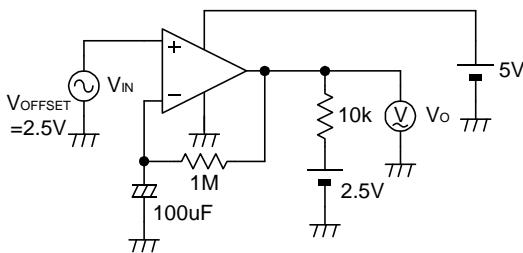
$$I_{SI} : V_{IN+} = 2V, V_{IN-} = 3V, V_O = 0.5V$$

- Slew Rate



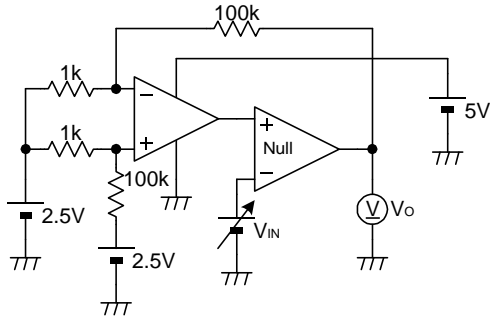
$$SR = \frac{\Delta V_O}{\Delta T_{RISE}}$$

- Gain-Bandwidth Product



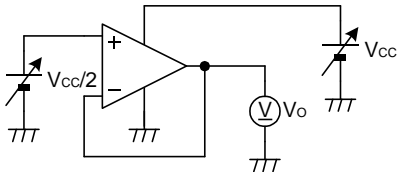
$$GB = \frac{V_O(f_T)}{V_{IN}(f_T)} \times f_T$$

• Open Circuit Voltage Gain



$$G_{VO} = 20 \log \left(101 \times \frac{-\Delta V_{IN}}{\Delta V_O} \right)$$

• Supply Voltage Rejection Ratio

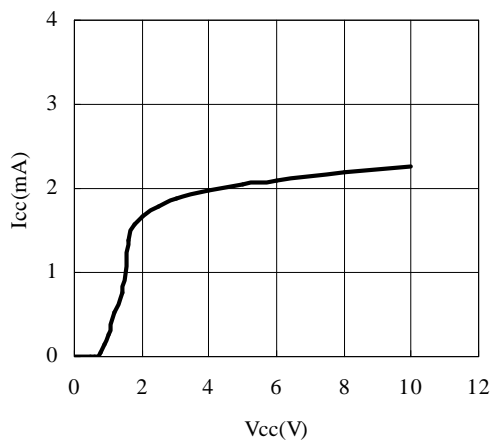


$$SVRR = 20 \log \frac{\Delta V_{CC}}{\Delta V_O}$$

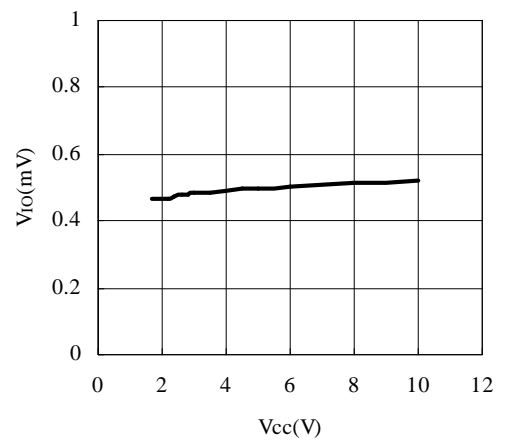
10. TYPICAL CHARACTERISTICS

(Ta=25°C, Vcc=5V)

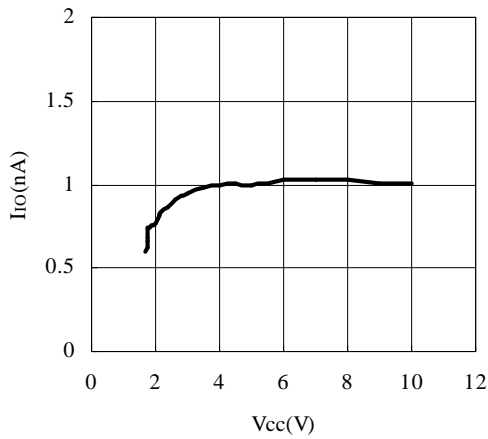
• Supply Current vs. Supply Voltage



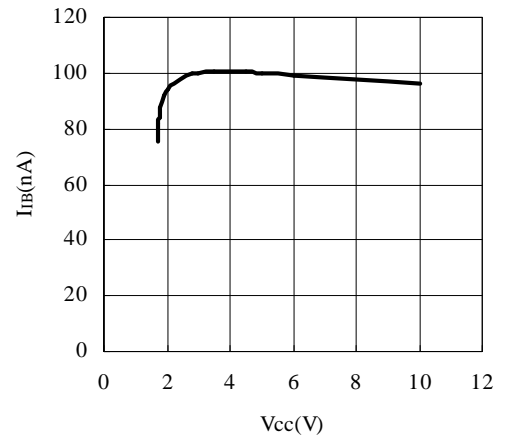
• Input Offset Voltage vs. Supply Voltage



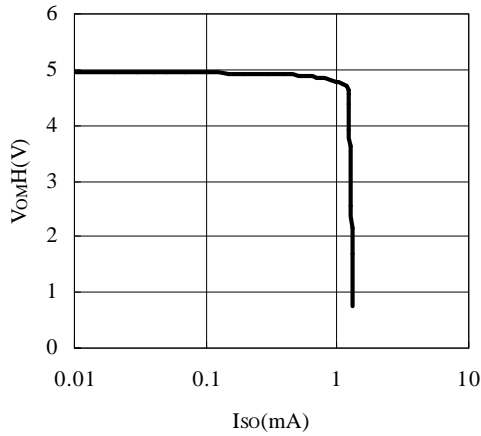
• Input Offset Current vs. Supply Voltage



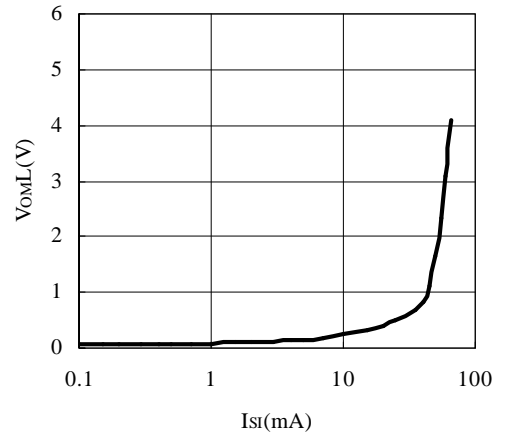
• Input Bias Current vs. Supply Voltage



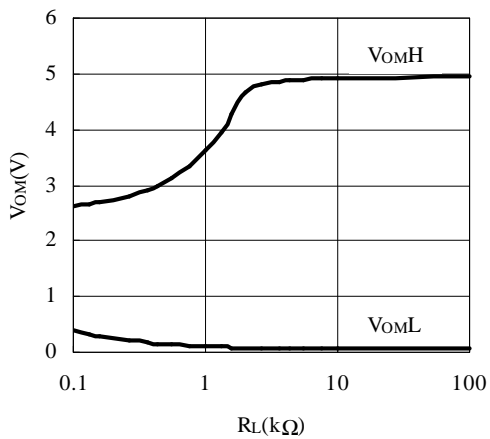
• Maximum High Output Voltage vs. Source Current
($V_{IN+}=3V, V_{IN-}=2V$)



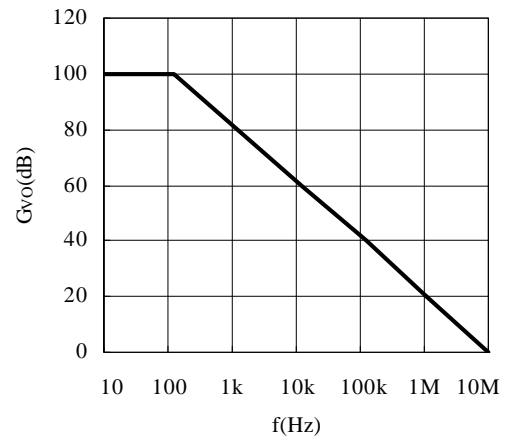
• Maximum Low Output Voltage vs. Sink Current
($V_{IN+}=2V, V_{IN-}=3V$)



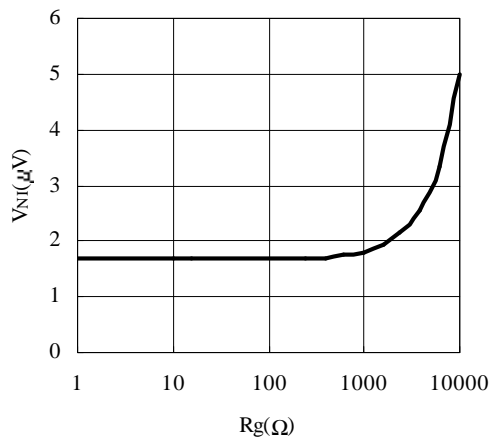
• Maximum Output Voltage vs. Load Resistance



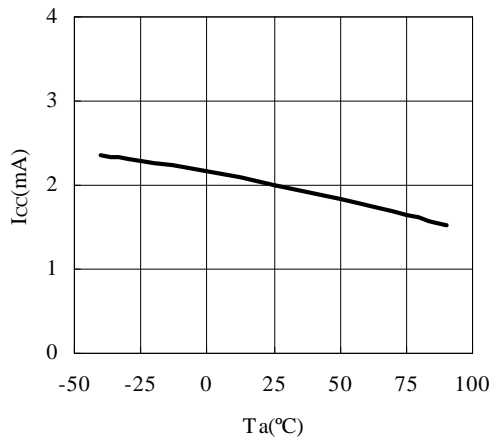
• Open Circuit Voltage Gain vs. Frequency



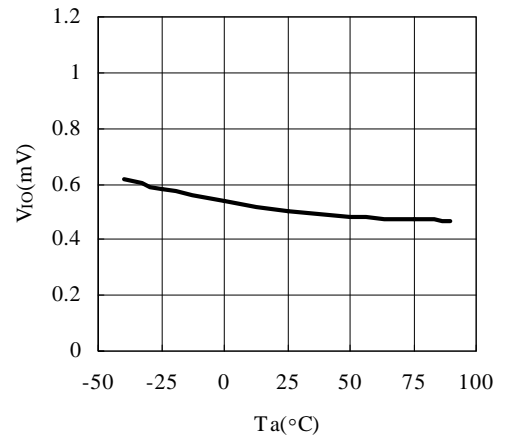
• Equivalent Input Noise Voltage vs. Source Resistance
(Gain=60dB)



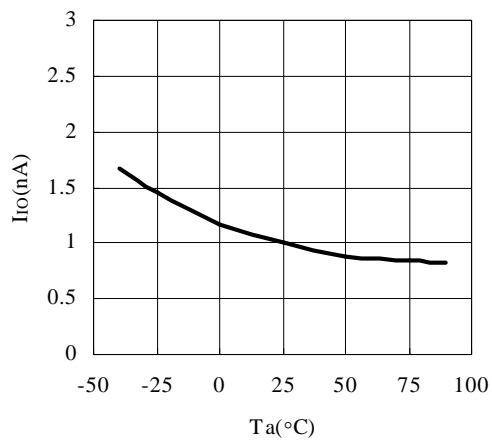
• Supply Current vs. Temperature



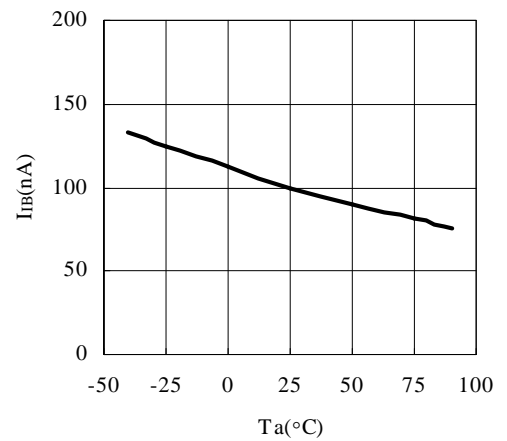
• Input Offset Voltage vs. Temperature



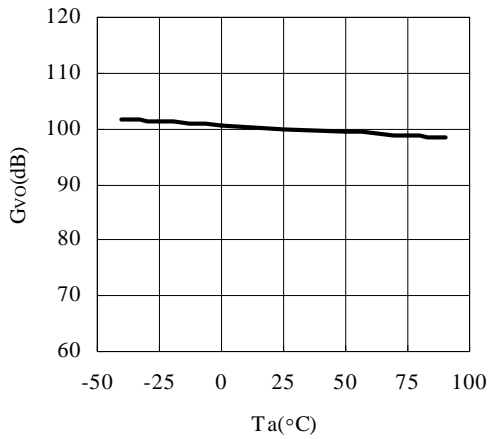
• Input Offset Current vs. Temperature



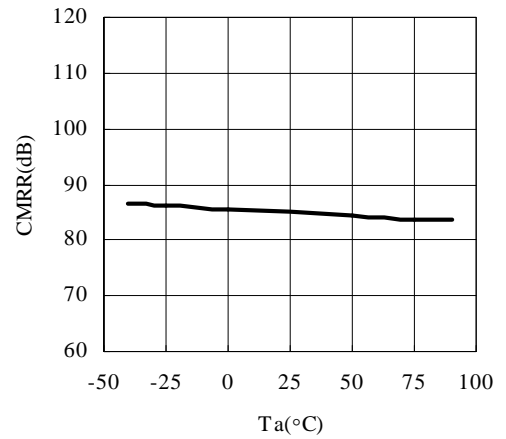
• Input Bias Current vs. Temperature



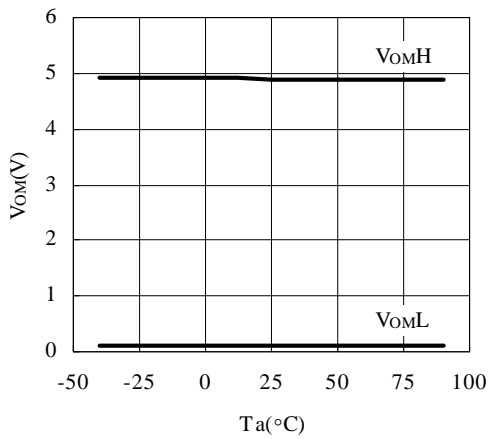
• Open Circuit Voltage Gain vs. Temperature



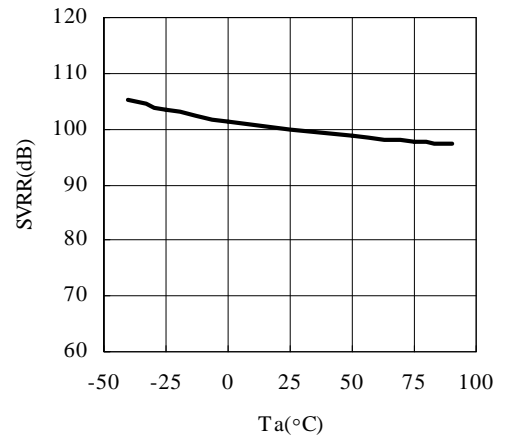
• Common-Mode Rejection Ratio vs. Temperature



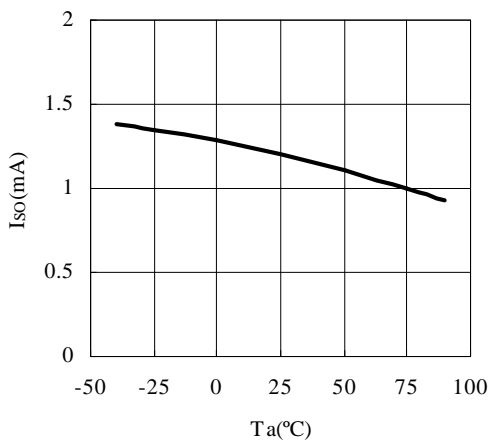
• Maximum Output Voltage vs. Temperature (R_L=5kΩ)



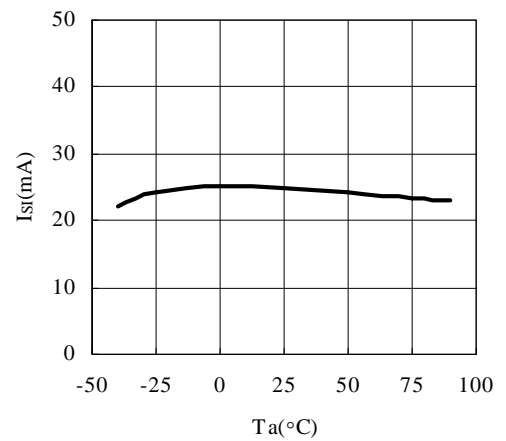
• Supply Voltage Rejection Ratio vs. Temperature



• Source Current vs. Temperature
(V_{IN+}=3V, V_{IN-}=2V, V_O=4.5V)



• Sink Current vs. Temperature
(V_{IN+}=3V, V_{IN-}=2V, V_O=0.5V)



11. NOTES

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